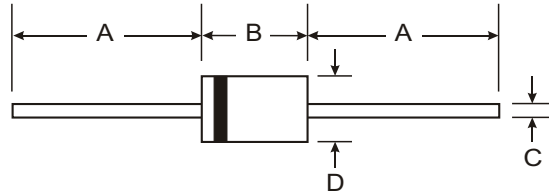


### Features

- Diffused Junction
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0



### Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: DO-41 0.30 grams (approx)  
A-405 0.20 grams (approx)
- Mounting Position: Any
- Marking: Type Number

Dim	DO-41 Plastic		A-405	
	Min	Max	Min	Max
A	25.40	—	25.40	—
B	4.06	5.21	4.10	5.20
C	0.71	0.864	0.53	0.64
D	2.00	2.72	2.00	2.70

All Dimensions in mm

"L" Suffix Designates A-405 Package  
No Suffix Designates DO-41 Package

### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	1N 4001/L	1N 4002/L	1N 4003/L	1N 4004/L	1N 4005/L	1N 4006/L	1N 4007/L	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	V <sub>RWM</sub>								
DC Blocking Voltage	V <sub>R</sub>								
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @ T <sub>A</sub> = 75°C	I <sub>O</sub>	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	30							A
Forward Voltage @ I <sub>F</sub> = 1.0A	V <sub>FM</sub>	1.0							V
Peak Reverse Current @ T <sub>A</sub> = 25°C at Rated DC Blocking Voltage @ T <sub>A</sub> = 100°C	I <sub>RM</sub>	5.0 50							μA
Typical Junction Capacitance (Note 2)	C <sub>j</sub>	15				8			pF
Typical Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	100							K/W
Maximum DC Blocking Voltage Temperature	T <sub>A</sub>	+150							°C
Operating and Storage Temperature Range (Note 3)	T <sub>j</sub> , T <sub>STG</sub>	-65 to +175							°C

- Notes:
1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.
  2. Measured at 1. MHz and applied reverse voltage of 4.0V DC.
  3. JEDEC Value

